

# Status of scintillator and SiPM tests at CERN

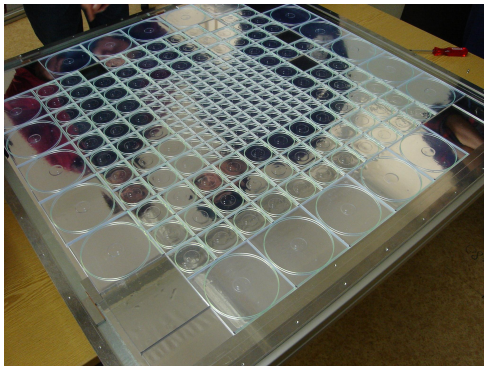
Laszlo Varga (CERN, Eotvos Lorand University HU)

June 2, 2015  
CLIC Detector and Physics  
Collaboration Meeting



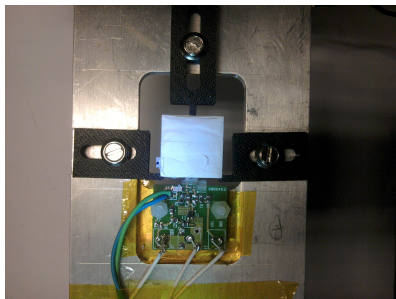
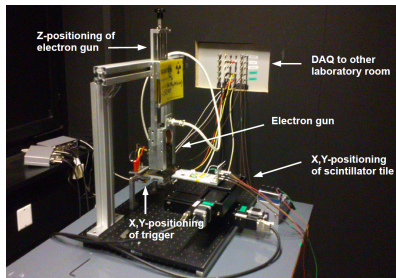
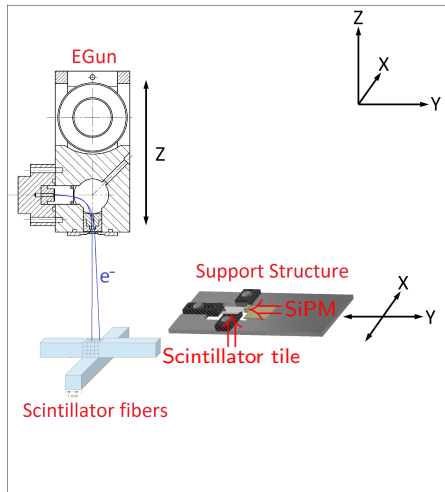
# Motivation

- Improve understanding of scintillators and SiPMs and related systematic effects in CALICE AHCAL test beam experiments
- Characterize new generation of SiPMs
- Characterize impact of scintillator wrappings and tile size on measured light yield

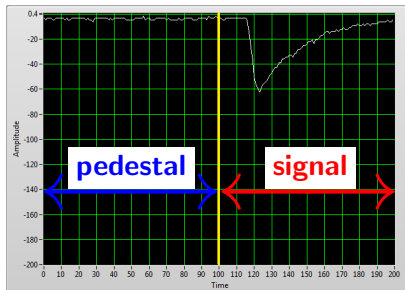


Sensitive layer of the CALICE AHCAL

# The setup at CERN

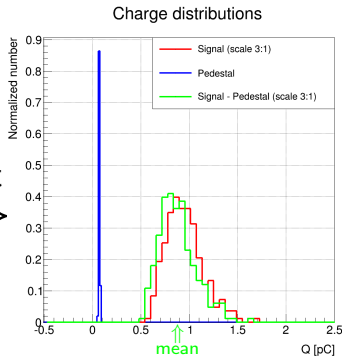


# The method of the charge measurement



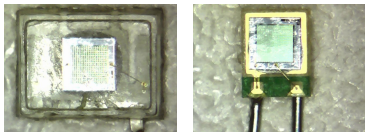
$$\int dt$$

$$\Rightarrow$$



- Two time windows for pedestal and signal measurement
- Convert signal and pedestal response to charge by time integration
- Subtract pedestal from signal event-by-event
- Get the mean of the Signal-Pedestal distribution

# Calibration of the SiPM - Temperature dependence

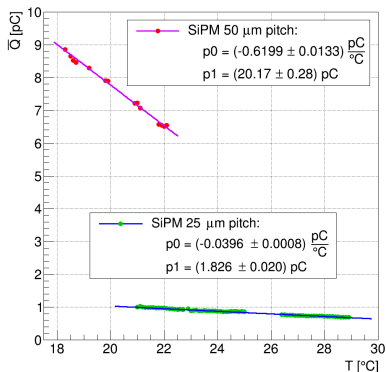


- SiPMs from Hamamatsu:

- ⇒ Type No.: S10943-8584(X), Serial No.: 11770, **50 $\mu$ m pitch**, Number of pixels: 400

- ⇒ Type No.: S10362-11-025P, Serial No.: 225, **25 $\mu$ m pitch**, Number of pixels: 1600

Mean of charge vs. Temperature



- Used the EGun and the wrapped  $\square 20 \times 2$  tile

- Fit  $\bar{Q}$  vs T dependence with linear fit function:

$$\Rightarrow \bar{Q} = p0 \cdot T + p1$$

- **SiPM with 50 $\mu$ m pitch:**  $\Delta \bar{Q}_{T=19^{\circ}\text{C}} \approx 7.4 \frac{\%}{\text{C}}$

- **SiPM with 25 $\mu$ m pitch:**  $\Delta \bar{Q}_{T=19^{\circ}\text{C}} \approx 3.7 \frac{\%}{\text{C}}$

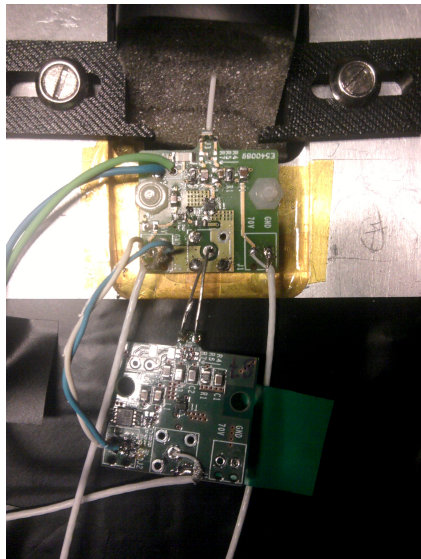
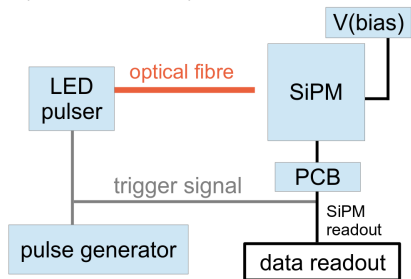
- $\left. \frac{\bar{Q}_{25\mu\text{m}}}{\bar{Q}_{50\mu\text{m}}} \right|_{(T=22^{\circ}\text{C})} < 1, \left. \frac{\text{Gain}_{25\mu\text{m}}}{\text{Gain}_{50\mu\text{m}}} \right|_{(T=22^{\circ}\text{C})} < 1$

- In order to cope with the reduced gain in the 25 $\mu$ m SiPM, a 2nd amplification stage was installed

# Calibration of the SiPM - Gain

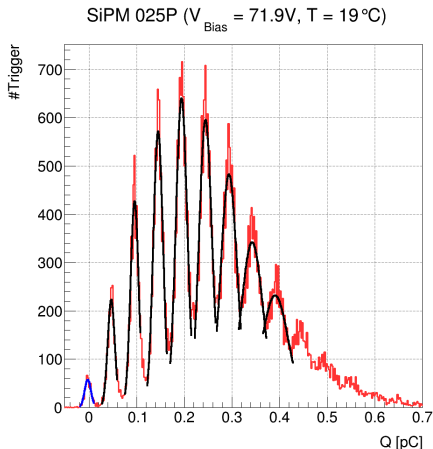
- Replace scintillator tile by optical fiber, which is connected to an LED pulser
- Measure signal from individual photons for gain calibration

Simplified schematic of the setup for the characterization of the SiPM:

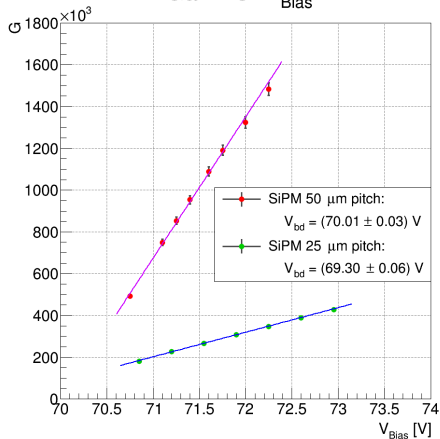


# Calibration of the SiPM - Gain

- Measure the charge of single photons
- Measure T simultaneously  
 $\Rightarrow$  Temperature correction of  $Q^{\text{measured}}$  for each measurement
- Fit separate Gaussian functions to the first n peaks (here n=9)  
 $\Rightarrow$  The first peak is the **noise peak** (i=1)  
 $\Rightarrow$   $i \geq 2$  photoelectron peak
- Calculate  $\overline{\Delta Q} \Rightarrow$  Gain (=G)
- Repeat the method for different  $V_{\text{Bias}}$  values  
 $\Rightarrow$   $G - V_{\text{Bias}}$  dependence



# Calibration of the SiPM - Gain

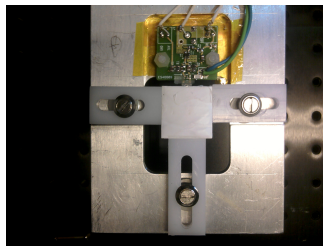
Gain vs.  $V_{Bias}$ 

- Fit  $G - V_{Bias}$  with linear function
- $G \propto (V_{Bias} - V_{bd})$
- $Slope_{50\mu m}(T_{ref}) \approx 6 \cdot Slope_{25\mu m}(T_{ref})$   
 $\Rightarrow$  SiPM with 25  $\mu m$  has less  $V_{Bias}$  dependence
- $G_{25\mu m}(V_{op}, T_{ref}) \approx 4 \cdot G_{50\mu m}(V_{op}, T_{ref})$

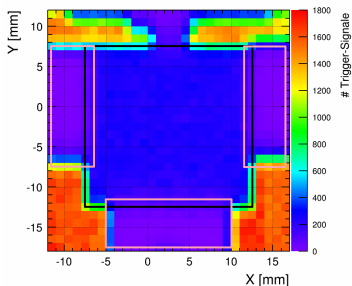


# Improvement of the experimental setup

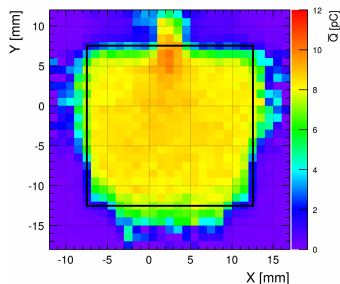
- At the beginning:  
use "high-material" tile holders to hold the scintillator in place
- The #Trigger map shows the transparency of the support structure
- Even if the electron beam does not hit the scintillator, stray particles produced in the tile holders leak into scintillator resulting in a measurable signal



#Trigger map of a tilescan

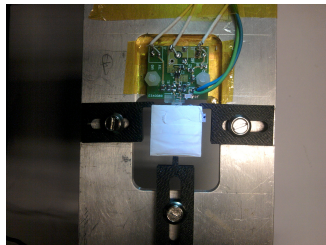


$\bar{Q}$  map of a scintillator tile

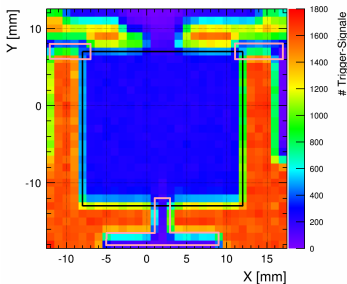


# Improvement of the experimental setup

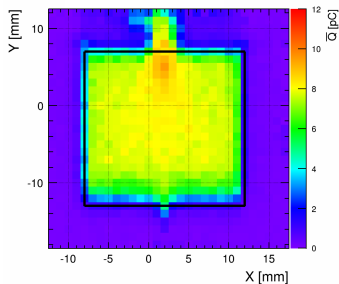
- Reduce material in tile holders close to the tile as much as possible
  - ⇒ The signal from stray particles disappeared on the  $\bar{Q}$  map



#Trigger map of a tilescan



$\bar{Q}$  map of a scintillator tile



# Comparison of different tiles

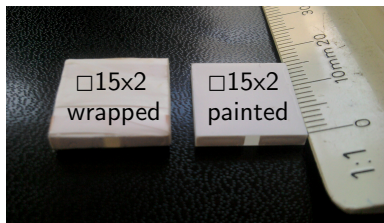
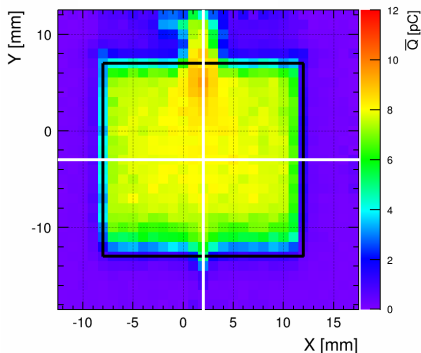
- Tested scintillator tiles:

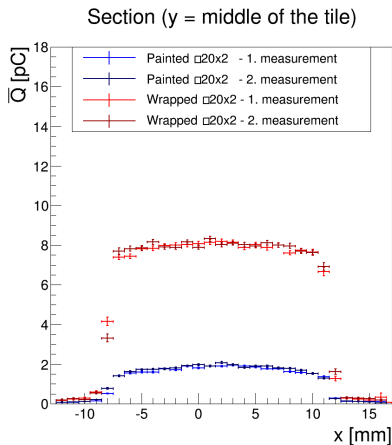
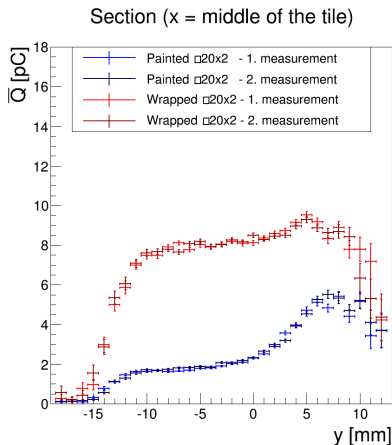
- ⇒ coating:

- wrapping (3M foil)
- reflection paint

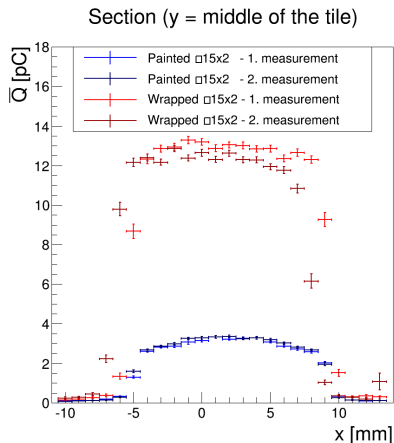
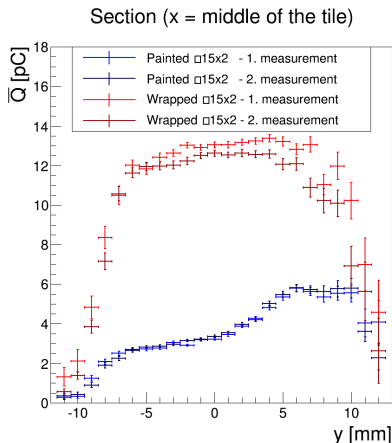
- ⇒ size:

- $20 \times 20 \text{ mm}^2$
- $15 \times 15 \text{ mm}^2$



Slices of the  $\square 20\text{mm}$  tiles

- The light yield of the wrapped tile is  $\sim 4$  times higher than for the painted tile
- $Y\bar{Q}$  section: peak at the SiPM;  $X\bar{Q}$  section: uniformity
- The measurements agree within uncertainties

Slices of the  $\square 15\text{mm}$  tiles

- Same light yield difference regarding the coating as observed for the  $\square 20\text{mm}$  tiles
- The light yield of the  $\square 15\text{mm}$  tiles is  $\sim 1.5$  times higher than for the  $\square 20\text{mm}$  tiles. This effect is understandable due to the aspect ratio of the tiles with different sizes

# Summary and Outlook

- Comparison of the SiPMs:
  - ⇒ SiPM with  $25\mu m$  pitch has less Temperature dependence compared to the SiPM with  $50\mu m$
  - ⇒ SiPM with  $25\mu m$  pitch has less  $V_{Bias}$  dependence compared to the SiPM with  $50\mu m$
- Comparison of the tiles:
  - ⇒ The light yield of the wrapped tile is  $\sim 4$  times higher than for the painted tile independent of the size
  - ⇒ The light yield of the  $\square 15mm$  tiles is  $\sim 1.5$  times higher than for the  $\square 20mm$  tiles independent of the coating
- Next steps:
  - ⇒ Study smaller scintillator tiles (eg.  $\square 10mm$ )
  - ⇒ Detailed test of the reproducibility of the tile scans
  - ⇒ Temperature measurements with a Peltier-element chamber
  - ⇒ Tile scan with several tiles next to each other to understand cross-talk between the tiles